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Total Pages: 03

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SEMICONDUCTOR PHYSICS BS-115A

Time: Three Hours]

[Maximum Marks: 75

Note: Attempt *Five* questions in all, selecting at least *one* question from each Unit. All questions carry equal marks.

Unit I

- 1. (a) What is Bravais lattice? Explain different types of Brvais lattices in three dimensions.
- (b) Discuss the hexagonal closed packed (hcp) structure and determine the c/a ratio for hcp structure. 8
 - 2. (a) What do you mean by point defects in solids?Derive an expression for concentration of Frankel defects at thermal equilibrium.
 - (b) Explain the different types of bonding in solids and give one example of each.

Unit II

3. (a) Describe the de-Broglie matter waves and establish the correspondence between particle concepts and wave concepts.

(b)	Explain the group velocity and particle velocity.
	Prove that group velocity is less than the phase
	velocity in dispersive medium.
(a)	State Heisenberg's uncertainty principle. Prove the
	non-existence of the electron inside the nucleus
	using uncertainty principle. 7
(b)	Derive the time independent one-dimensional
	Schrodinger wave equation for s non-relativistic a
	free particle. Also give the significance of the wave
	function.
	Unit III
	Office and the second of the s
(a)	What are the drawbacks of classical free electron
	theory? Discuss the quantum theory of free electron
	in a one-dimensional box.
(b)	Discuss the Fermi-Dirac distribution function. Plot
je dim	this function for various temperatures including
	0 K.
(a)	Explain the concept of effective mass of the electron
	on the basis of band theory of solids.

coefficient and mention some of the applications of

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this effect.

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6.

Unit IV

7.	(a)	What are Semiconductors? Explain the intrinsic
		and extrinsic semiconductors.
•	(b)	Derive an expression for carrier concentration in
		n-type semiconductors. What would be the position
		of Fermi level in the same?
8.	(a)	What are Bipolar Junction Transistors (BJT)?
	* . 350	Explain the characteristics of the bipolar junction
		transistors.
× ,	(b)	Describe the principle, construction and working of
		a semiconductor laser.